²⁵⁸Db α decay (1.9 s) 2009He20

History			
Туре	Author	Citation	Literature Cutoff Date
Full Evaluation	Balraj Singh	NDS 156, 1 (2019)	31-Jan-2019

Parent: ²⁵⁸Db: E=0+x; J^{π} =(1⁻); $T_{1/2}$ =1.9 s 5; Q(α)=9500 50; % α decay=64 10

 258 Db-J^{π},T_{1/2}: From 258 Db Adopted Levels in the ENSDF database (August 2017 update).

²⁵⁸Db-Q(α): From 2017Wa10.

²⁵⁸Db-%α decay: %α=64 10 (from ²⁵⁸Db Adopted Levels in the ENSDF database (August 2017 update)).

2009He20, 2016He15: ²⁵⁸Db produced in ²⁰⁹Bi(⁵⁰Ti,n),E=236 MeV, ⁵⁰Ti beam from the ECR source of the UNILAC at GSI. The Evaporation residues (ERs) were separated by the velocity filter SHIP and implanted into a position-sensitive 16-strip Si PIPS detector for detecting ERs, conversion electrons, and subsequent α -decays or spontaneous fission (SF) events. Escaped products into the backward hemisphere were detected by a box of six Si wafers. The x rays were detected by a Ge clover detector consisting of four crystals. Measured correlations between ERs, x rays, ce, α -decay and SF events. Deduced isomeric states and half-lives.

²⁵⁴Lr Levels

E(level)

0+x

 α radiations

 $E\alpha$ E(level)Comments9196 100+x $E\alpha$: from 2009He20. Other: 9172 15 (1985He22). The 9172 α was resolved in two components, first in
1999He11, then in more detail in 2009He20, where 9166 α was assigned to the decay of 4.3-s activity, and
9196 α to the decay of 1.9-s activity of 258 Db.